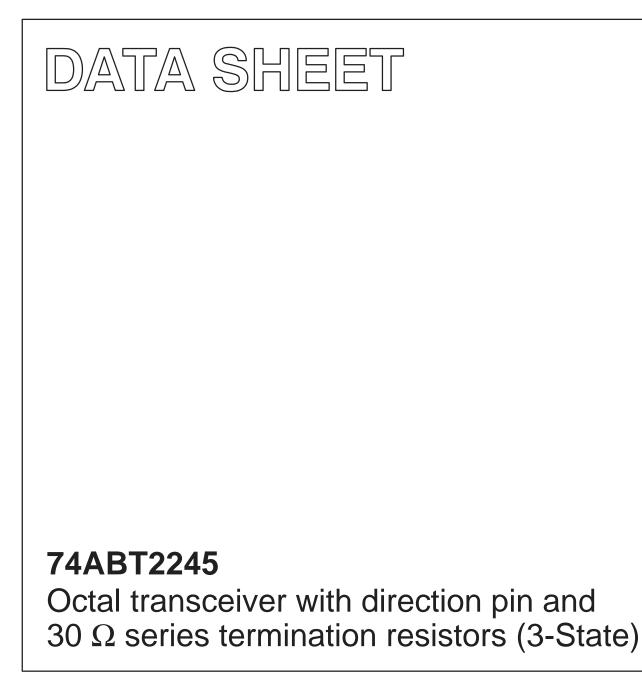
INTEGRATED CIRCUITS



Product data Supersedes data of 1998 Jan 16 2002 Dec 17



74ABT2245

FEATURES

- Octal bidirectional bus interface
- 3-State buffers
- Output capability: +12 mA / -32 mA
- Latch-up protection exceeds 500 mA per Jedec Std 17
- ESD protection exceeds 2000 V per MIL STD 833 Method 3015 and 200 V per Machine Model
- Power-up 3-State
- Live insertion/extraction permitted
- Same as 74ABT245-1
- Outputs include series resistance of 30 Ω, making external termination resistors unnecessary
- Inputs are disabled during 3-State mode

DESCRIPTION

The 74ABT2245 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed.

The 74ABT2245 device is an octal transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable (\overline{OE}) input for easy cascading and a Direction (DIR) input for direction control.

The 74ABT2245 is designed with 30 Ω series resistance in both the HIGH and LOW states of the output. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus receivers/transmitters.

The 74ABT2245 is the same as the 74ABT245-1. The part number has been changed to reflect industry standards.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25 °C; GND = 0 V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	C _L = 50 pF; V _{CC} = 5 V	3.9	ns
C _{IN}	Input capacitance DIR, OE	$V_I = 0 V \text{ or } V_{CC}$	4	pF
C _{I/O}	I/O pin capacitance	Outputs disabled; $V_0 = 0 V \text{ or } V_{CC}$	7	pF
I _{CCZ}	Total supply current	Outputs disabled; V_{CC} = 5.5 V	50	μΑ

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	PART NUMBER	DWG NUMBER
20-Pin plastic SO	–40 °C to +85 °C	74ABT2245D	SOT163-1
20-Pin Plastic SSOP Type II	–40 °C to +85 °C	74ABT2245DB	SOT339-1
20-Pin Plastic TSSOP Type I	–40 °C to +85 °C	74ABT2245PW	SOT360-1

PIN CONFIGURATION

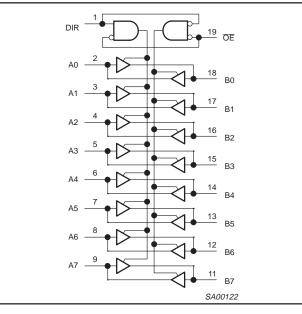
DIR [20 V _{CC}
A0 [2	19 OE
A1 [3	18 B0
A2 [4	17 B1
A3 [5	16 B2
A4 [6	15 B3
A5 [7	14 B4
A6 [8	13 B5
A7 [9	12 B6
GND [10	11 B7
	S	A00121

PIN DESCRIPTION

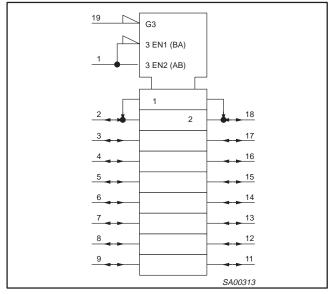
PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	DIR	Direction control input
2, 3, 4, 5, 6, 7, 8, 9	A0 – A7	Data inputs/outputs (A side)
18, 17, 16, 15, 14, 13, 12, 11	B0 – B7	Data inputs/outputs (B side)
19	ŌĒ	Output enable input (active-LOW)
10	GND	Ground (0 V)
20	V _{CC}	Positive supply voltage

74ABT2245

LOGIC SYMBOL



LOGIC SYMBOL IEEE/IEC



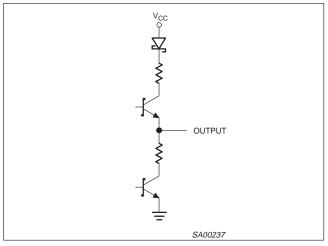
FUNCTION TABLE

INP	UTS	INPUTS/C	OUTPUTS
OE	DIR	An	Bn
L	L	An = Bn	Inputs
L	Н	Inputs	Bn = An
н	Х	Z	Z

H = High voltage level L = Low voltage level

X = Don't care Z = High impedance "off" state

SCHEMATIC OF EACH OUTPUT



74ABT2245

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V _I < 0 V	-18	mA
VI	DC input voltage ³		-1.2 to +7.0	V
I _{ОК}	DC output diode current	V _O < 0 V	-50	mA
V _{OUT}	DC output voltage ³	output in Off or HIGH state	-0.5 to +5.5	V
I _{OUT}	DC output current	output in LOW state	128	mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

 The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
		Min	Мах	1
V _{CC}	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V _{CC}	V
VIH	HIGH-level input voltage	2.0	-	V
V _{IL}	LOW-level Input voltage	-	0.8	V
I _{OH}	HIGH-level output current	-	-32	mA
I _{OL}	LOW-level output current	-	12	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	5	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

DC ELECTRICAL CHARACTERISTICS

						LIMITS			
SYMBOL	PARAMETER		TEST CONDITIONS	T _{ar}	_{nb} = +25	°C	T _{amb} = to +8	–40 °C 35 °C	UNIT
			Γ		Тур	Max	Min	Max	
V _{IK}	Input clamp vol	tage	$V_{CC} = 4.5 \text{ V}; \text{ I}_{IK} = -18 \text{ mA}$	-	-0.9	-1.2	-	-1.2	V
			V_{CC} = 4.5 V; I_{OH} = –3 mA; V_{I} = V_{IL} or V_{IH}	2.5	2.9	-	2.5	-	V
V _{OH}	HIGH-level outp	out voltage	V_{CC} = 5.0 V; I_{OH} = –3 mA; V_{I} = V_{IL} or V_{IH}	3.0	3.4	-	3.0	-	V
			V_{CC} = 4.5 V; I_{OH} = –32 mA; V_{I} = V_{IL} or V_{IH}	2.0	2.4	-	2.0	-	V
M			V_{CC} = 4.5 V; I _{OL} = 5 mA; V _I = V _{IL} or V _{IH}	-	0.32	0.55	-	0.55	V
V _{OL}	LOW-level outp	out voltage	V_{CC} = 4.5 V; I _{OL} = 12 mA; V _I = V _{IL} or V _{IH}	-	0.5	0.8	-	0.8	V
	Input leakage	Control pins	V_{CC} = 5.5 V; V_I = GND or 5.5 V	-	±0.01	±1.0	-	±1.0	μA
1 ₁	current	Data pins	V_{CC} = 5.5 V; V_{I} = GND or 5.5 V	-	±5	±100	-	±100	μΑ
I _{OFF}	Power-off leaka	ige current	V_{CC} = 0.0 V; V1 or V_O \leq 4.5 V	-	±5.0	±100	-	±100	μA
I _{PU} /I _{PD}	Power-up/dowr output current ³	o 3-State	V_{CC} = 2.1 V; V_{O} = 0.5 V; V_{I} = GND or V_{CC} ; V _{OE} = Don't care	-	±5.0	±50	-	±50	μΑ
I _{IH} + I _{OZH}	3-State output I	ligh current	V_{CC} = 5.5 V; V_{O} = 2.7 V; V_{I} = V_{IL} or V_{IH}	-	5.0	50	-	50	μA
I _{IL} + I _{OZL}	3-State output I	_ow current	V_{CC} = 5.5 V; V_{O} = 0.5 V; V_{I} = V_{IL} or V_{IH}	-	-5.0	-50	-	-50	μA
I _{CEX}	Output high lea	kage current	V_{CC} = 5.5 V; V_{O} = 5.5 V; V_{I} = GND or V_{CC}	-	5.0	50	-	50	μA
Ι _Ο	Output current ¹		$V_{CC} = 5.5 \text{ V}; V_{O} = 2.5 \text{ V}$	-40	-100	-180	-40	-180	mA
I _{CCH}			V_{CC} = 5.5 V; Outputs HIGH, V_{I} = GND or V_{CC}	-	50	250	-	250	μA
I _{CCL}	Quiescent supp	olv current	V_{CC} = 5.5 V; Outputs LOW, V_{I} = GND or V_{CC}	-	24	30	-	30	mA
I _{CCZ}		,	V_{CC} = 5.5 V; Outputs 3-State; V _I = GND or V _{CC}	-	50	250	-	250	μΑ
			Outputs enabled, one input at 3.4 V, other inputs at V _{CC} or GND; V _{CC} = 5.5 V	-	0.5	1.5	-	1.5	mA
ΔI_{CC}	Additional supp input pin ²	ly current per	Outputs 3-State, one data input at 3.4 V, other inputs at V _{CC} or GND; V _{CC} = 5.5 V	-	50	250	-	250	μΑ
			Outputs 3-State, one enable input at 3.4 V, other inputs at V _{CC} or GND; V _{CC} = 5.5 V	-	0.5	1.5	-	1.5	mA

NOTES:

1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

2. This is the increase in supply current for each input at 3.4 V. 3. This parameter is valid for any V_{CC} between 0 V and 2.1 V with a transition time of up to 10 msec. From V_{CC} = 2.1 V to V_{CC} = 5 V \pm 10%, a transition time of up to 100 µsec is permitted.

74ABT2245

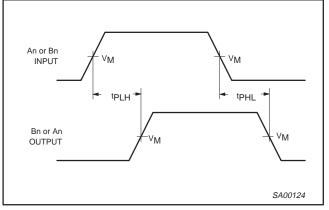
AC CHARACTERISTICS

GND = 0 V; t_R = t_F = 2.5 ns; CL = 50 pF, RL = 500 Ω

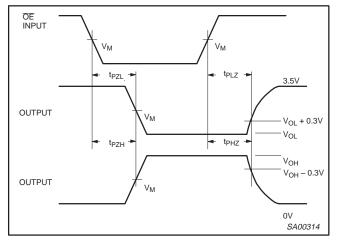
					LIMI	TS		
SYMBOL	PARAMETER	WAVEFORM	T _a V	_{mb} = +25 ° _{CC} = +5.0	°C V	T _{amb} = -40 ° V _{CC} = +5.0	°C to +85 °C 0 V ±0.5 V	UNIT
			Min	Тур	Мах	Min	Max	
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	1	1.0 1.0	2.8 3.9	4.2 5.0	1.0 1.0	4.7 5.4	ns
t _{PZH} t _{PZL}	Output enable time to HIGH and LOW level	2	1.3 3.0	3.5 5.5	4.6 7.0	1.3 3.0	5.5 7.8	ns
t _{PHZ} t _{PLZ}	Output disable time from HIGH and LOW Level	2	1.5 1.0	4.0 3.4	5.4 4.6	1.5 1.0	6.3 5.0	ns

AC WAVEFORMS

 V_{M} = 1.5 V, V_{IN} = GND to 3.0 V



Waveform 1. Waveforms Showing the Input to Output Propagation Delays

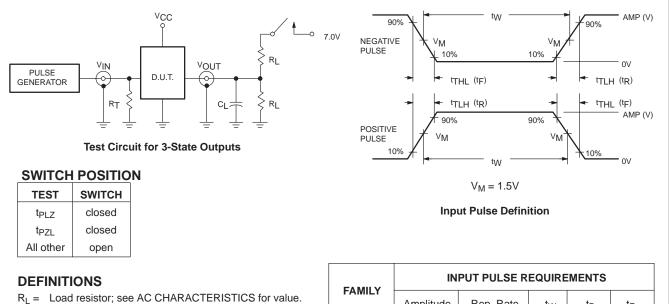


Waveform 2. Waveforms Showing the 3-State Output Enable and Disable Times

74ABT2245

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TEST CIRCUIT AND WAVEFORMS



- C_L = Load resistor, see AC CHARACTERISTICS for value. C_L = Load capacitance includes jig and probe capacitance;
- see AC CHARACTERISTICS for value. R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

FAMILY	IN	PUT PULSE R	EQUIRE	MENTS	
FAMILI	Amplitude	Rep. Rate	t _W	t _R	t _F
74ABT	3.0V	1MHz	500ns	2.5ns	2.5ns

SA00012

Product data

Шγ

Octal transceiver with direction pin and 30 Ω series termination resistors (3-State)

SO20: plastic small outline package; 20 leads; body width 7.5 mm

2002 Dec 17

	1) >pin	1 index		 			10 → w 🕅	l		2 A1		detail X		A ₃) ↓ ↓ ↓ ↓	A V		
						0 L	· · · ·		5 scale		1	0 mm J						
DIMENS	ions (i	nch dim	ension	s are de	erived fr	om the	origina	l mm di	imensio	ns)								
	BIONS (i A max.	nch dim A ₁	ension: A ₂	s are de A ₃	erived fr b _p	om the	origina D ⁽¹⁾	l mm di E ⁽¹⁾	imensio e	ns) H _E	L	Lp	Q	v	w	У	z ⁽¹⁾	θ
	A										L 1.4	Lp 1.1 0.4	Q 1.1 1.0	v 0.25	w 0.25	y 0.1	z ⁽¹⁾ 0.9 0.4	
UNIT	A max.	A ₁ 0.30	A 2 2.45	A ₃	b p 0.49	c 0.32	D ⁽¹⁾ 13.0	E ⁽¹⁾ 7.6	e	H E		1.1	1.1			-	0.9	θ 8° 0°
UNIT mm nches ote	A max. 2.65	A ₁ 0.30 0.10 0.012 0.004	A2 2.45 2.25 0.096 0.089	A ₃ 0.25 0.01	b _p 0.49 0.36 0.019 0.014	c 0.32 0.23 0.013 0.009	D ⁽¹⁾ 13.0 12.6 0.51 0.49	E ⁽¹⁾ 7.6 7.4 0.30 0.29	e 1.27 0.050	H E 10.65 10.00 0.419	1.4	1.1 0.4 0.043	1.1 1.0 0.043	0.25	0.25	0.1	0.9 0.4 0.035	8°
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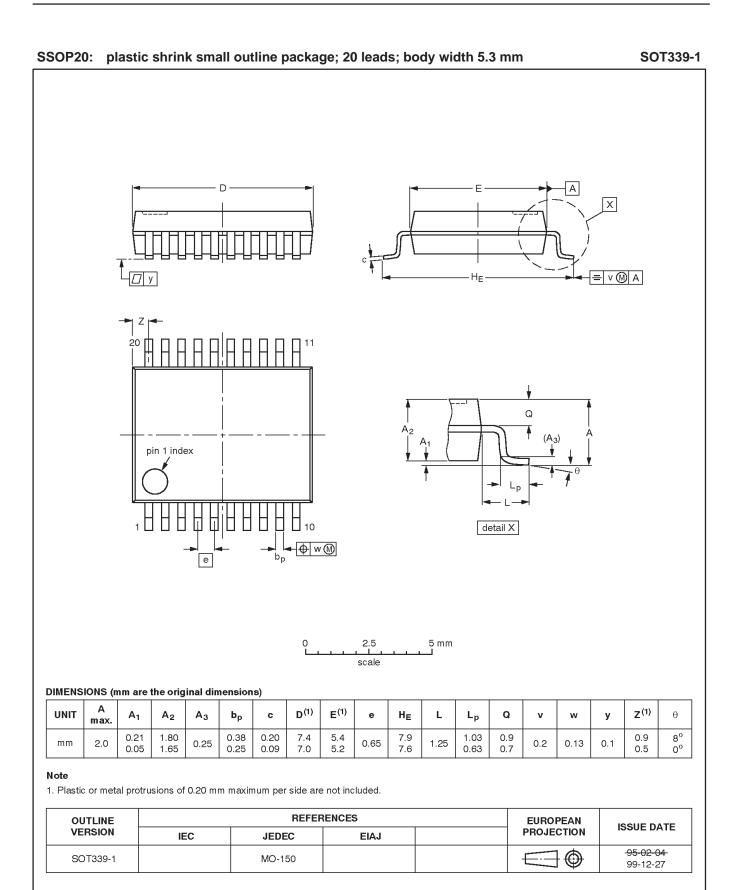
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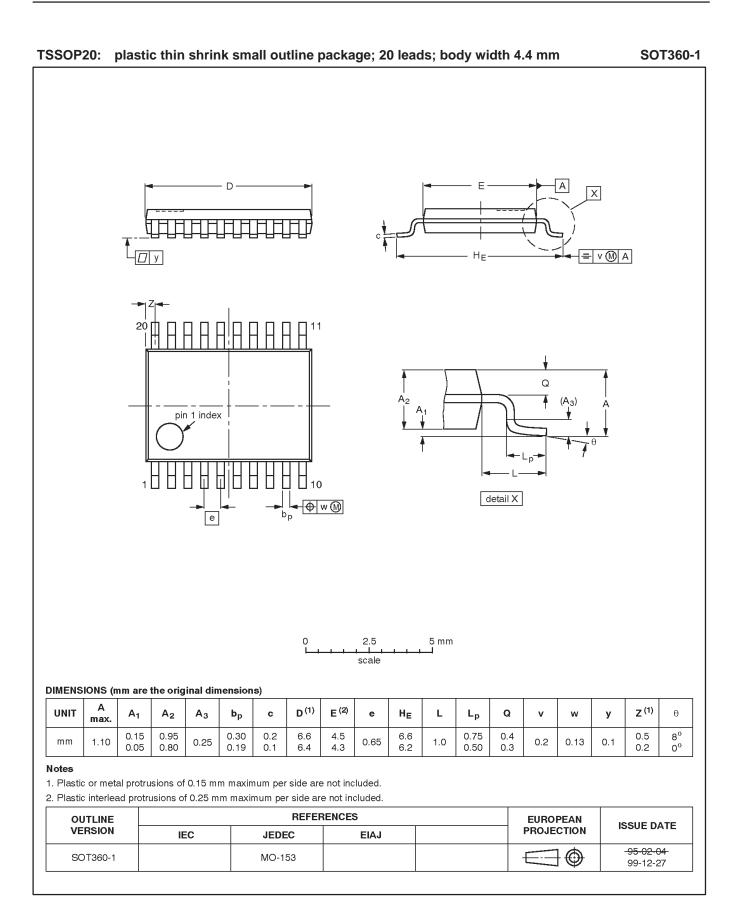
Product data

74ABT2245

Product data



74ABT2245



74ABT2245

REVISION HISTORY

Rev	Date	Description
_3	20021217	Product data (9397 750 10846); ECN 853-1761 29292 of 12 December 2002. Supersedes data of 16 January 1998 (9397 750 03468).
		Modifications:
		 Ordering information table: remove "North America" column; remove 74ABT2245N package offering.
_2	19980116	Product specification (9397 750 03468); ECN 853-1761 18865 of 16 January 1998. Supersedes data of 1995 September 06.
_1	19950906	Product specification; ECN 853-1761 15701 of 06 September 1995.

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Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2] [3]}	Definitions
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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